TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

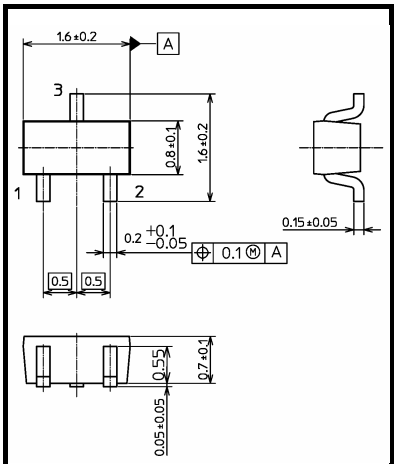
SSM3K37FS

○ High Speed Switching Applications

○ Analog Switch Applications

- 1.5Vdrive
- Low ON-resistance $R_{DS(ON)}$ = 5.60 Ω (max) (@V_{GS} = 1.5 V)
  $R_{DS(ON)}$ = 4.05 Ω (max) (@V_{GS} = 1.8 V)
  $R_{DS(ON)}$ = 3.02 Ω (max) (@V_{GS} = 2.5 V)
  $R_{DS(ON)}$ = 2.20 Ω (max) (@V_{GS} = 4.5 V)

Unit: mm



1. Gate
2. Source
3. Drain

SSM	
JEDEC	—
JEITA	—
TOSHIBA	2-2H1B

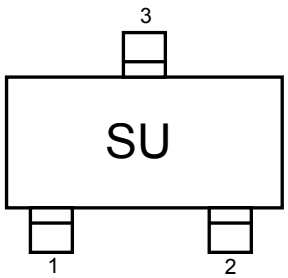
Weight: 2.4mg(typ.)

Absolute Maximum Ratings (Ta = 25°C)

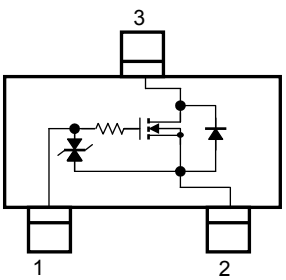
Characteristics		Symbol	Rating	Unit
Drain-Source voltage		V_{DSS}	20	V
Gate-Source voltage		V_{GSS}	± 10	V
Drain current	DC	I_D	200	mA
	Pulse	I_{DP}	400	
Power dissipation		P_D	100	mW
Channel temperature		T_{ch}	150	°C
Storage temperature range		T_{stg}	−55 to 150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Marking



Equivalent Circuit (Top View)



Start of commercial production
2011-01

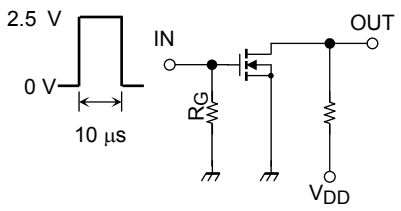
Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Drain-source breakdown voltage		$V_{(BR)\ DSS}$	I_D = 1 mA, V_{GS} = 0 V	20	—	—	V
		$V_{(BR)\ DSX}$	I_D = 1 mA, V_{GS} = -10 V	12	—	—	
Drain cut-off current		I_{DSS}	V_{DS} = 20 V, V_{GS} = 0 V	—	—	1	μA
Gate leakage current		I_{GSS}	V_{GS} = ±10 V, V_{DS} = 0 V	—	—	±1	μA
Gate threshold voltage		V_{th}	V_{DS} = 3 V, I_D = 1 mA	0.35	—	1.0	V
Forward transfer admittance		$\|Y_{fs}\|$	V_{DS} = 3 V, I_D = 100 mA (Note2)	0.14	0.28	—	S
Drain-source ON-resistance		$R_{DS\ (ON)}$	I_D = 100 mA, V_{GS} = 4.5 V (Note2)	—	1.65	2.20	Ω
			I_D = 50 mA, V_{GS} = 2.5 V (Note2)	—	2.16	3.02	
			I_D = 20 mA, V_{GS} = 1.8 V (Note2)	—	2.66	4.05	
			I_D = 10 mA, V_{GS} = 1.5 V (Note2)	—	3.07	5.60	
Input capacitance		C_{iss}	V_{DS} = 10 V, V_{GS} = 0 V, f = 1 MHz	—	12	—	pF
Output capacitance		C_{oss}		—	5.5	—	
Reverse transfer capacitance		C_{rss}		—	4.1	—	
Switching time	Turn-on time	t_{on}	V_{DD} = 10 V, I_D = 100 mA	—	18	—	ns
	Turn-off time	t_{off}	V_{GS} = 0 to 2.5 V, R_G = 50 Ω	—	36	—	
Drain-Source forward voltage		V_{DSF}	I_D = -200 mA, V_{GS} = 0 V (Note2)	—	-0.89	-1.2	V

Note2: Pulse test

Switching Time Test Circuit

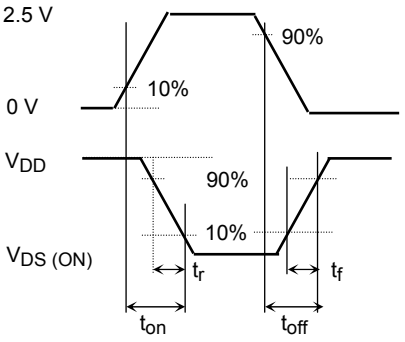
(a) Test Circuit



V_{DD} = 10 V
R_G = 50Ω
Duty ≤ 1%
V_{IN} : t_r, t_f < 5 ns
Common source
Ta = 25°C

(b) V_{IN}

(c) V_{OUT}



Precaution

Let V_{th} be the voltage applied between gate and source that causes the drain current (I_D) to be low (1mA for the SSM3K37FS). Then, for normal switching operation, $V_{GS(on)}$ must be higher than V_{th}, and $V_{GS(off)}$ must be lower than V_{th}. This relationship can be expressed as: $V_{GS(off)} < V_{th} < V_{GS(on)}$.

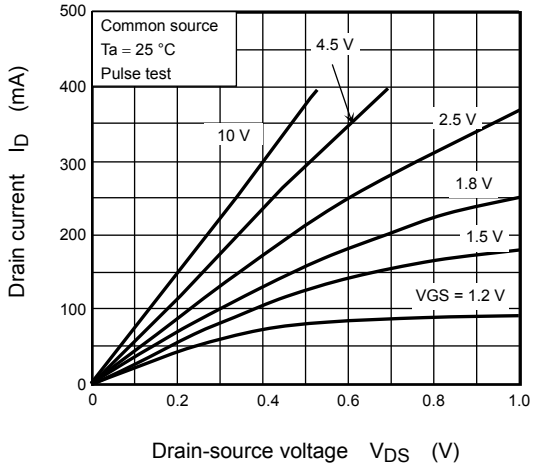
Take this into consideration when using the device.

Handling Precaution

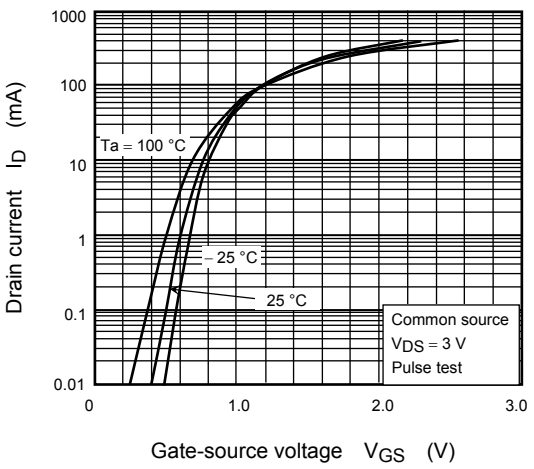
When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.

Thermal resistance $R_{th\ (ch\text{-}a)}$ and power dissipation P_D vary depending on board material, board area, board thickness and pad area. When using this device, please take heat dissipation into consideration

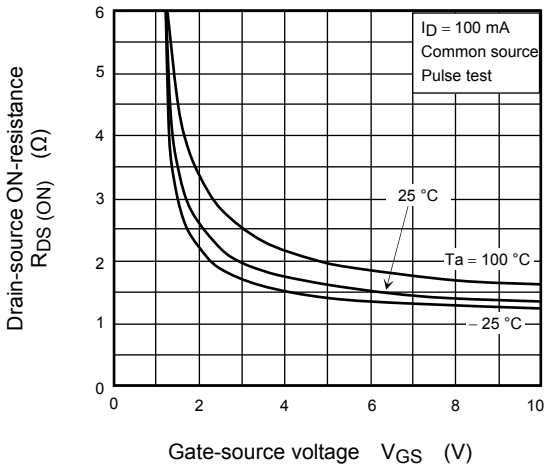
$I_D - V_{DS}$



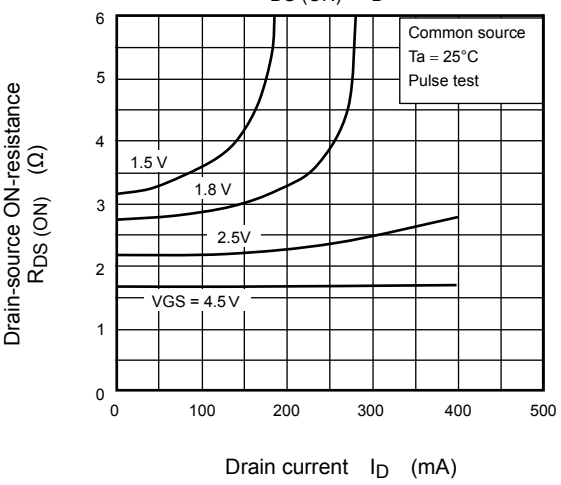
$I_D - V_{GS}$



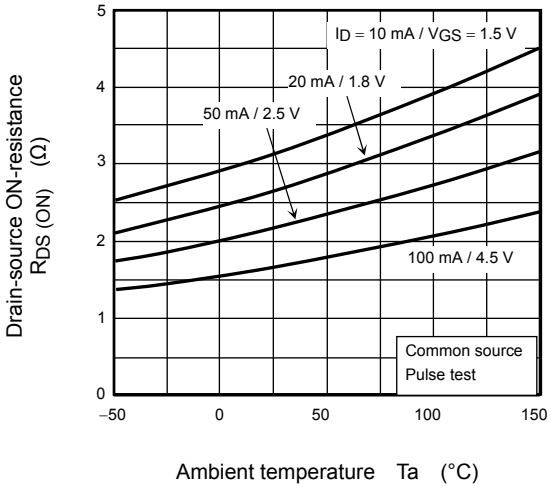
$R_{DS\ (ON)} - V_{GS}$



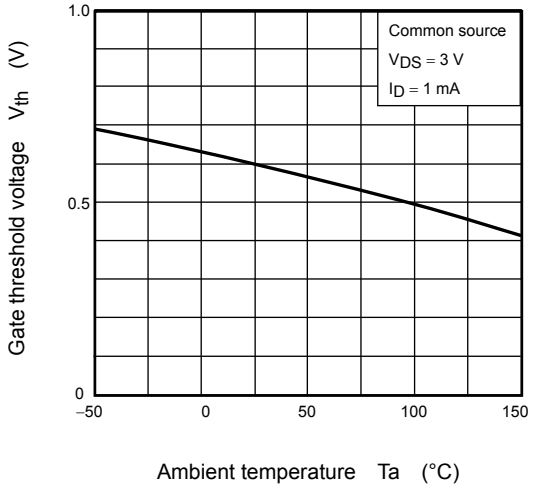
$R_{DS\ (ON)} - I_D$

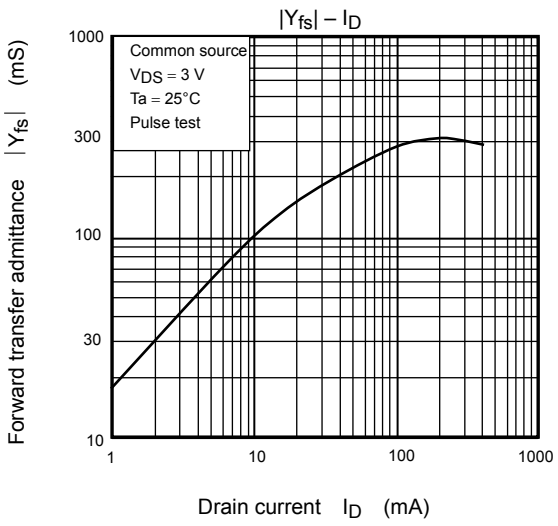


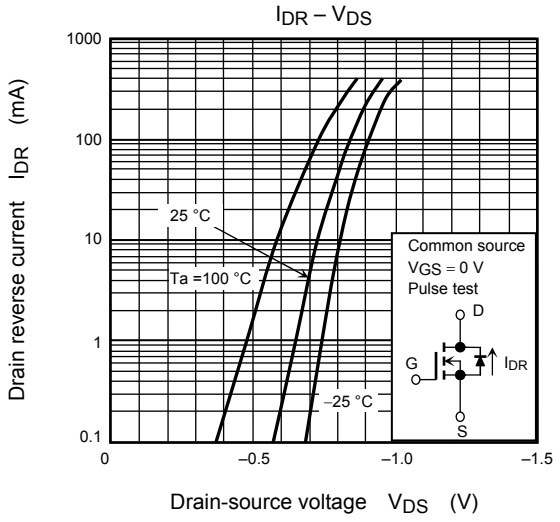
$R_{DS\ (ON)} - Ta$

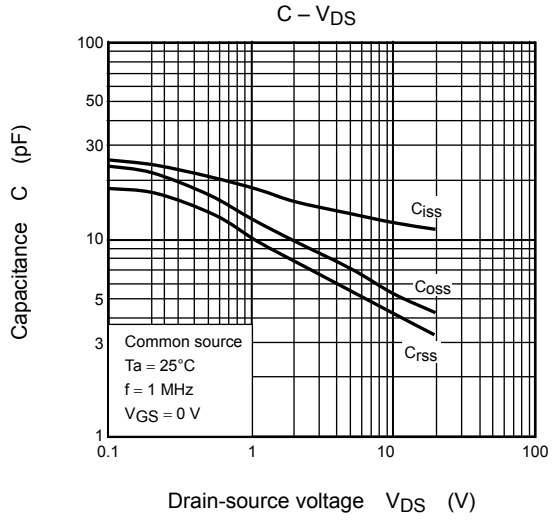


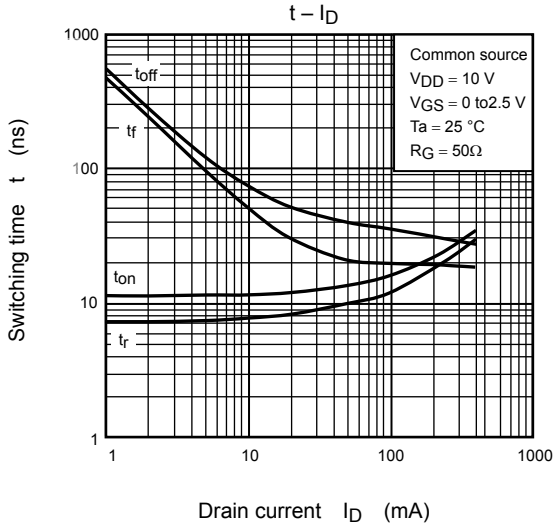
$V_{th} - Ta$

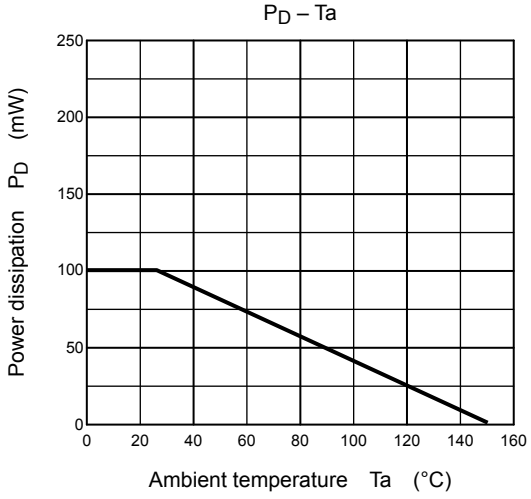



|Yfs| – ID
Common source
VDS = 3 V
Ta = 25°C
Pulse test
Forward transfer admittance |Yfs| (mS)
Drain current ID (mA)
1000
300
100
30
10
1
10
100
1000


IDR – VDS
Common source
VGS = 0 V
Pulse test
25 °C
Ta =100 °C
–25 °C
D
G
S
IDR
Drain reverse current IDR (mA)
Drain-source voltage VDS (V)
1000
100
10
1
0.1
0
–0.5
–1.0
–1.5


C – VDS
Common source
Ta = 25°C
f = 1 MHz
VGS = 0 V
Ciss
Coss
Crss
Capacitance C (pF)
Drain-source voltage VDS (V)
100
50
30
10
5
3
1
0.1
1
10
100


t – ID
Common source
VDD = 10 V
VGS = 0 to2.5 V
Ta = 25 °C
RG = 50Ω
toff
tf
ton
tr
Switching time t (ns)
Drain current ID (mA)
1000
100
10
1
1
10
100
1000


PD – Ta
Power dissipation PD (mW)
Ambient temperature Ta (°C)
250
200
150
100
50
0
0
20
40
60
80
100
120
140
160

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